



# SMT PHEMT LOW NOISE AMPLIFIER, 0.3 - 3.0 GHz

### **Typical Applications**

The HMC374 / HMC374E is ideal for:

- Cellular/PCS/3G
- WCS, MMDS & ISM
- Fixed Wireless & WLAN
- Private Land Mobile Radio

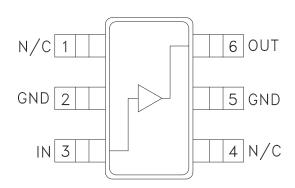
### **Features**

Single Supply: Vdd = +2.75 to +5.5V

Low Noise Figure: 1.5 dB High Output IP3: +37 dBm

No External Matching Required

### **Functional Diagram**



### **General Description**

The HMC374 & HMC374E are general purpose broad band Low Noise Amplifiers (LNA) for use in the 0.3 - 3 GHz frequency range. The LNA provides 15 dB of gain and a 1.5 dB noise figure from a single positive supply of +2.75 to +5.5V. The low noise figure coupled with a high P1dB (22 dBm) and high OIP3 (37 dBm) make this part ideal for cellular applications. The compact LNA design utilizes on-chip matching for repeatable gain and noise figure performance. To minimize board area the design is offered in a low cost SOT26 package that occupies only 0.118" x 0.118".

## Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd = +5V

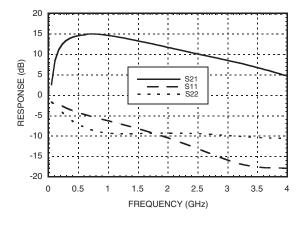
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	0.3 - 1.0			1.0 - 2.0		2.0 - 3.0		GHz		
Gain	12	15		10	13		6	9		dB
Gain Variation Over Temperature		0.01	0.02		0.01	0.02		0.01	0.02	dB/°C
Noise Figure		1.5	1.9		1.6	2.0		1.8	2.2	dB
Input Return Loss		5			8			13		dB
Output Return Loss		7			9			9		dB
Output 1 dB Compression (P1dB)		22			22			22		dBm
Saturated Output Power (Psat)		23			23			23		dBm
Output Third Order Intercept (IP3)		37			37			37		dBm
Supply Current (Idd) (Vdd = +5V)		90			90			90		mA



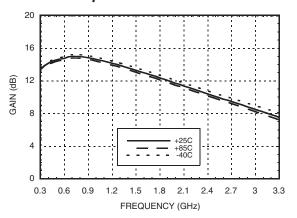


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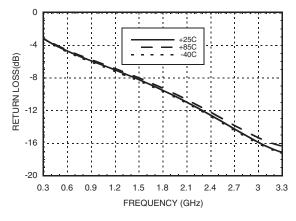
### **Broadband Gain & Return Loss**



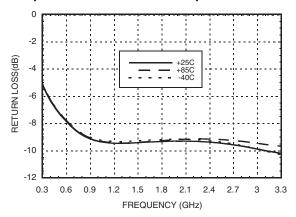
### Gain vs. Temperature



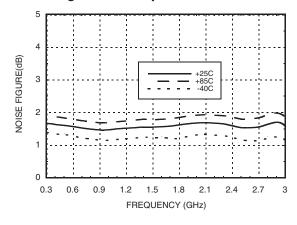
### Input Return Loss vs. Temperature



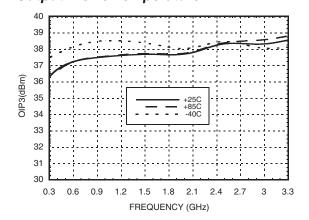
### Output Return Loss vs. Temperature



### Noise Figure vs. Temperature



### Output IP3 vs. Temperature

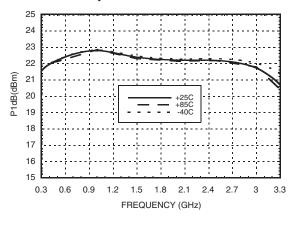




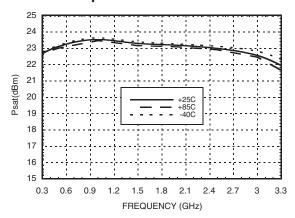


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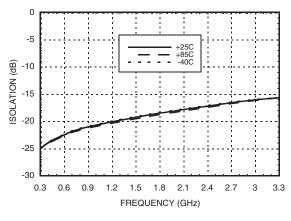
### P1dB vs. Temperature



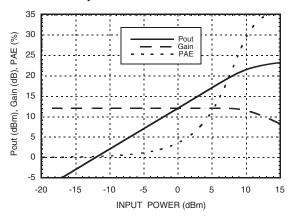
### Psat vs. Temperature



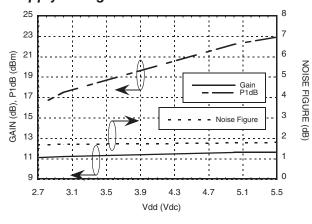
### Reverse Isolation vs. Temperature



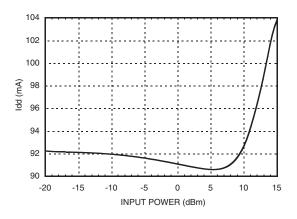
### Power Compression @ 2 GHz



## Gain, Noise Figure & Power vs. Supply Voltage @ 2 GHz



### Current vs. Power @ 2 GHz







## SMT PHEMT LOW NOISE AMPLIFIER, 0.3 - 3.0 GHz

### **Absolute Maximum Ratings**

Drain Bias Voltage (Vdd)	+7.0 Vdc	
RF Input Power (RFIN)(Vdd = +5.0 Vdc)	15 dBm	
Channel Temperature	150 °C	
Continuous Pdiss (T = 85 °C) (derate 7.5 mW/°C above 85 °C)	0.488 W	
Thermal Resistance (channel to lead)	133 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	

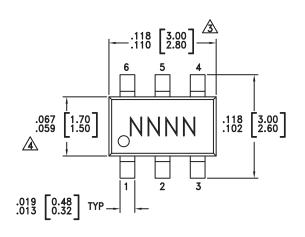
### Typical Supply Current vs. Vdd

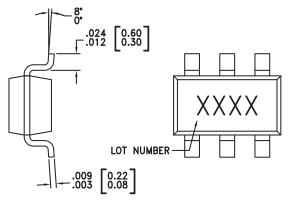
Vdd (V)	Idd (mA)
2.7	89
3.0	89
5.0	90
5.5	90



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

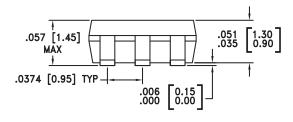
### **Outline Drawing**





#### NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.



### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC374	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H374 XXXX
HMC374E	HMC374E RoHS-compliant Low Stress Injection Molded Plastic		MSL1 [2]	374E XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260  $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX





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### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1,4	N/C	These pins may be connected to RF/DC ground. Performance will not be affected.	
2, 5	GND	These pins must be connected to RF/DC ground.	GND
3	IN	This pin is DC coupled. An off-chip DC blocking capacitor is required.	IN OUT
6	OUT	RF output and DC Bias for the output stage. See application circuit for off-chip components.	

### **Application Circuit**

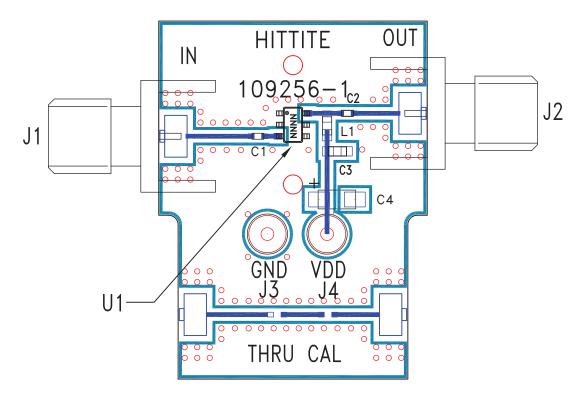
Recommende	ed Component Values				
C1, C2	150 pF	]			
С3	1,000 pF	]			∨ Vdd
C4	4.7 μF	]			7 4 4
L1	27 nH	]			C4
	RFIN O	C1 	3 HMC374	C3 L1	RFOUT C2





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### **Evaluation PCB**



### List of Materials for Evaluation PCB 109258 [1]

Item	Description	
J1, J2	PCB Mount SMA Connector	
J3, J4	DC Pin	
C1, C2	150 pF Capacitor, 0402 Pkg.	
C3	1000 pF Capacitor, 0603 Pkg.	
C4	4.7 Capacitor, Tantalum	
L1	27 nH Inductor, 0603 Pkg.	
U1	HMC374 / HMC374E Amplifier	
PCB [2]	109256 Evaluation PCB	

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

<sup>[2]</sup> Circuit Board Material: Roger 4350

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